in Tables 1 and 2 are more than an order of magnitude lower than those previously quoted for $\mathrm{Ca}_{2} \mathrm{IrO}_{4}$ and $\mathrm{CaIrO}_{3}$. We therefore believe the $\mathrm{Ir}-\mathrm{O}$ bond length reported here to be more reliable than that determined in the earlier X-ray studies.

This work demonstrates that although absorption of neutrons is a significant problem when working with iridium compounds, the application of an absorption correction makes data refinement to a high standard possible.

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# Structure of a Synthetic Double-Layer Silicate, $\mathbf{R b}_{2} \mathbf{C u}_{2} \mathbf{S i}_{8} \mathbf{O}_{\mathbf{1 9}}$ 

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#### Abstract

Rb}_{2} \mathrm{Cu}_{2} \mathrm{Si}_{8} \mathrm{O}_{19}, \quad M_{r}=826.7\), monoclinic, $P 2_{1} / m, a=11.450$ (2), $b=8.409$ (2), $c=9.847$ (1) $\AA$, $\beta=95.28(1)^{\circ}, \quad V=944.1$ (3) $\AA^{3}, \quad Z=2, \quad D_{x}=$ $2.91 \mathrm{Mg} \mathrm{m}^{-3}, \quad \lambda($ Mo $K \alpha)=0.71069 \AA, \quad \mu=$


 $8.35 \mathrm{~mm}^{-1}, F(000)=792, T=298 \mathrm{~K}$, final $R=0.045$ for 1411 independent reflections. The structure consists of staggered double sheets of $\mathrm{SiO}_{4}$ tetrahedra. The sheets consist of six-membered rings. The doubling of sheets forms ten-membered rings viewed parallel to the $c$ axis. These double sheets are linked by pairs of Cu atoms in four coordination sites. Rb atoms are located in the cavities of these tenmembered rings and have eight and ten nearest neighbours. The structure of this silicate is classified as $\mathrm{Rb}_{2} \mathrm{Cu}_{2}\left\{u B, 2_{\infty}^{2}\right\}\left[{ }^{4} \mathrm{Si}_{8} \mathrm{O}_{19}\right]$ after the classification symbol of Liebau [Structural Chemistry of Silicates (1985), pp. 69-75, 121-126, 232, 250, 267. Berlin: Springer].Introduction. This study was initiated with the purposes of exploring new phases of silicates and contri-

[^0]buting to the crystal chemistry of alkali copper silicates. Until now, two sodium copper silicates (Kawamura \& Kawahara, 1976, 1977), a lithium copper silicate (Kawamura, Kawahara \& Iiyama, 1978), a potassium copper silicate (Kawamura \& Iiyama, 1981) and a caesium copper silicate (Heinrich \& Gramlich, 1982) have been investigated. The hydrothermal synthesis of a series of rubidium copper silicates, $\mathrm{Rb}_{x} \mathrm{Cu}_{y} \mathrm{Si}_{p} \mathrm{O}_{q}$, was attempted and several new phases were obtained. The present paper reports the structure of one of the newly synthesized phases.

Experimental. Hydrothermal synthesis of the title compound was carried out with a test-tube-type apparatus ( $723-873 \mathrm{~K}, 700-2500 \mathrm{~kg} \mathrm{~cm}^{-2}, 3 \mathrm{~d}$ ) with reagent mixtures of $\mathrm{CuSO}_{4} \cdot 5 \mathrm{H}_{2} \mathrm{O}, \mathrm{SiO}_{2}$ and $\mathrm{Rb}_{2} \mathrm{CO}_{3}$. Crystals of $\mathrm{Rb}_{2} \mathrm{Cu}_{2} \mathrm{Si}_{8} \mathrm{O}_{19}$ were deep bluish and less than 0.1 mm in size. The size of the crystal is approximately proportional to the pressure value. The chemical composition of the product was determined by X-ray microprobe analysis. A crystal with dimensions $0.02 \times 0.03 \times 0.01 \mathrm{~mm}$ was used for

Table 1. Atomic positional parameters $\left(\times 10^{4}\right)$ and equivalent isotropic temperature factors with e.s.d.'s in parentheses

| $B_{\text {eq }}=(4 / 3) \sum_{i} \sum_{j} \boldsymbol{\beta}_{i j} \mathbf{a}_{i} . \mathbf{a}_{j}$. |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | $x$ | $y$ | $z$ | $B_{\text {eq }}\left(\AA^{2}\right)$ |
| Cu | 5185 (1) | 4929 (2) | 8499 (1) | 1.31 (2) |
| Rb (1) | 4422 (2) | 7500 | 4740 (2) | 3.02 (4) |
| Rb (2) | 236 (1) | 2500 | 8967 (1) | 2.36 (3) |
| $\mathrm{Si}(1)$ | 2839 (2) | 689 (3) | 6587 (2) | 1.20 (6) |
| Si(2) | 7414 (2) | 4347 (3) | 741 (2) | 1.30 (6) |
| $\mathrm{Si}(3)$ | 8890 (2) | 663 (3) | 5652 (2) | 1.24 (5) |
| Si(4) | 2236 (2) | 626 (4) | 1937 (2) | 1.35 (6) |
| $\mathrm{O}(1)$ | 7657 (10) | 2500 | 1110 (10) | 2.32 (27) |
| $\mathrm{O}(2)$ | 5821 (5) | 9729 (9) | 3130 (6) | 1.81 (16) |
| $\mathrm{O}(3)$ | 6065 (5) | 278 (9) | 300 (6) | 1.62 (16) |
| $\mathrm{O}(4)$ | 7733 (6) | 461 (8) | 4640 (6) | 1.56 (15) |
| $\mathrm{O}(5)$ | 0 | 0 | 5000 | 3.00 (29) |
| O (6) | 8787 (5) | 9779 (9) | 7086 (6) | 1.95 (17) |
| $\mathrm{O}(7)$ | 7882 (5) | 9609 (8) | 2075 (6) | 1.51 (14) |
| $\mathrm{O}(8)$ | 3464 (6) | 5009 (11) | 2476 (6) | 2.41 (18) |
| $\mathrm{O}(9)$ | 1760 (5) | 5179 (10) | 457 (5) | 1.90 (16) |
| $\mathrm{O}(10)$ | 927 (12) | 7500 | 3994 (14) | 4.11 (36) |
| $\mathrm{O}(11)$ | 7438 (10) | 7500 | 3906 (9) | 1.93 (24) |
| $\mathrm{O}(12)$ | 2142 (12) | 2500 | 1619 (13) | 3.79 (37) |

data collection. The intensity data were collected on a Rigaku AFC-5R diffractometer with a generator operated by a rotating anode ( $40 \mathrm{kV}, 200 \mathrm{~mA}$ ) with graphite-monochromated Mo $K \alpha$ radiation in the $2 \theta-\omega$ scan mode. 3 standard reflections, $\overline{1} 2 \overline{1}, \overline{1} 21$, $\overline{1} \overline{1} \overline{2}$, were monitored every 150 reflections with a variation of $1.5 \%$. 2434 reflections were collected up to $2 \theta=60^{\circ}(0 \leq h \leq 16,0 \leq k \leq 11,-13 \leq l \leq 13)$, of which 1411 were observed with $I>3 \sigma(I)$. Lorentz-polarization corrections were made but no absorption correction. The cell dimensions were refined from 25 reflections with $27<2 \theta<44^{\circ}$.

Preliminary film methods gave $P 2_{1}$ or $P 2_{1} / m$. The existence of centres of symmetry was confirmed from Wilson statistics, so $P 2_{1} / m$ was obtained. The Cu atom was found from Patterson syntheses and the other atoms were located on the subsequent Fourier maps. Full-matrix least-squares refinement with anisotropic temperature factors, minimizing $\sum w(\Delta F)^{2}$, gave $R=0.045, w R=0.050, w=1 / \sigma(F)^{2}$, $S=0.94,149$ parameters refined, $(\Delta / \sigma)_{\text {max }}=0.14$, $(\Delta \rho)_{\text {max }, \min }=1.25,-1.02 \mathrm{e} \AA^{-3}$.

Atomic scattering factors for neutral atoms were used throughout the calculations (from International Tables for X-ray Crystallography, 1974, Vol. IV). The final positional parameters and equivalent isotropic thermal factors are shown in Table 1.* Calculations using the modified programs of UNICS (Sakurai, 1971) were carried out at the Data Processing Centre of Okayama University.

[^1]Discussion. A stereographic figure using $O R T E P$ (Johnson, 1965) of the structure of $\mathrm{Rb}_{2} \mathrm{Cu}_{2} \mathrm{Si}_{8} \mathrm{O}_{19}$ is shown in Fig. 1. This is isostructural with $\mathrm{Cs}_{2} \mathrm{Cu}_{2}-$ $\mathrm{Si}_{8} \mathrm{O}_{19}$ (Heinrich \& Gramlich, 1982). The structure consists of staggered double sheets of $\mathrm{SiO}_{4}$ tetrahedra parallel to the $b c$ plane. The sheets consist of six-membered rings. They are connected to each other through the apical O atoms of four $\mathrm{SiO}_{4}$ tetrahedra forming ten-membered rings parallel to the $a c$ plane. The mode of linkage of the double sheets is illustrated in Fig. 2. The double sheets are interconnected by $\mathrm{Cu}_{2} \mathrm{O}_{6}$ units. In these units, Cu atoms have square-planar coordinations with two squares sharing an edge.

The $\mathrm{SiO}_{4}$ double sheets can be expressed as $\mathrm{Rb}_{2} \mathrm{Cu}_{2}\left\{u B, 2_{\infty}^{2}\right\}\left[{ }^{4} \mathrm{Si}_{8} \mathrm{O}_{19}\right]$ after the classification symbol of Liebau (1985). Here, the symbol $u B$ stands for 'unbranched' and superscript 2 represents 'twodimensional framework'. The superscript 4 on Si corresponds to the number of tetrahedra within one


Fig. 1. Stereographic drawing of the structure of $\mathrm{Rb}_{2} \mathrm{Cu}_{2} \mathrm{Si}_{8} \mathrm{O}_{19}$. The figure represents the connection of one of the double sheets of $\mathrm{SiO}_{4}$ tetrahedra with Cu and Rb atoms. Here $\mathrm{Si}, \mathrm{Cu}$ and Rb atoms correspond to small solid, small open and large open circles, respectively.


Fig. 2. Diagram showing the linkage of the ten-membered rings in double sheets. The large open circles and small solid ones correspond to Rb and Cu atoms, respectively.

Table 2. Bond lengths $(\AA)$ and angles $\left({ }^{\circ}\right)$ with e.s.d.'s in parentheses

| $\mathrm{Cu}-\mathrm{O}\left(2^{\text {i }}\right.$ ) 1.8 | 1.894 (6) | $\mathrm{Si}(3)-\mathrm{O}\left(10^{\text {' }}\right.$ ) | 1.593 (4) |
| :---: | :---: | :---: | :---: |
| $\mathrm{Cu}-\mathrm{O}\left(3^{\text {v }}\right.$ ) 1.9 | 1.961 (6) | $\mathrm{Si}(4)-\mathrm{O}\left(6^{\text {iii) }}\right.$ ) | 1.619 (7) |
| $\mathrm{Cu}-\mathrm{O}\left(3^{i i}\right) \quad 1.95$ | 1.965 (5) | $\mathrm{Si}(4)-\mathrm{O}\left(8^{\text {xiii) }}\right.$ ) | 1.551 (7) |
| $\mathrm{Cu}-\mathrm{O}\left(\mathrm{Bi}^{\text {iii) }}\right.$ ( ${ }^{\text {(2) }}$ | 1.895 (7) | $\mathrm{Si}(4)-\mathrm{O}\left(9^{\text {xiii) }}\right.$ | 1.653 (6) |
| $\mathrm{Si}(1)-\mathrm{O}\left(2^{\text {iii }}\right.$ ) 1.5 | 1.574 (6) | $\mathrm{Si}(4)-\mathrm{O}(12)$ | 1.608 (4) |
| $\mathrm{Si}(1)-\mathrm{O}\left(4^{\text {xii }}\right) \quad 1.63$ | 1.637 (7) | $\mathrm{Rb}(1)-\mathrm{O}(2) \times 2^{\text {i }}$ | 3.010 (7) |
| $\mathrm{Si}(1)-\mathrm{O}$ (7ii) 1.63 | 1.637 (7) | $\mathrm{Rb}(1)-\mathrm{O}(2) \times 2^{\text {ive }}$ | 3.164 (7) |
| $\mathrm{Si}(1)-\mathrm{O}\left(11^{1}\right) \quad 1.6$ | 1.621 (4) | $\mathrm{Rb}(1)-\mathrm{O}(4) \times 2^{\text {v.iii }}$ | 3.111 (7) |
| $\mathrm{Si}(2)-\mathrm{O}(1) \quad 1.6$ | 1.613 (3) | $\mathrm{Rb}(1)-\mathrm{O}(8) \times 2{ }^{\text {ix }}$ | 3.180 (7) |
| $\mathrm{Si}(2)-\mathrm{O}\left(3^{\text {xii }}\right.$ ) 1.5 | 1.597 (6) | $\mathrm{Rb}(2)-\mathrm{O}(6) \times 2^{\text {vim }}$ | 3.294 (7) |
| $\mathrm{Si}(2)-\mathrm{O}\left(7^{\mathrm{ix}}\right) \quad 1.6$ | 1.629 (6) | $\mathrm{Rb}(2)-\mathrm{O}(7) \times 2^{\text {i.iij }}$ | 3.041 (7) |
| $\mathrm{Si}(2)-\mathrm{O}\left(9^{\mathrm{xV}}\right) \quad 1.6$ | 1.628 (6) | $\mathrm{Rb}(2)-\mathrm{O}(9) \times 2^{\text {x, }}$ i | 3.131 (7) |
| $\mathrm{Si}(3)-\mathrm{O}(4) \quad 1.92$ | 1.592 (6) | $\mathrm{Rb}(2)-\mathrm{O}(9) \times 2^{\text {ii.viii }}$ | 3.097 (7) |
| $\mathrm{Si}(3)-\mathrm{O}\left(5^{\mathrm{xiV}}\right) \quad 1.5$ | 1.577 (3) | $\mathrm{Rb}(2)-\mathrm{O}\left(10^{\text {x }}\right.$ ) | 3.092 (13) |
| $\mathrm{Si}(3)-\mathrm{O}\left(6^{\times \times \mathrm{i}}\right) \quad 1$. | 1.610 (7) | $\mathrm{Rb}(2)-\mathrm{O}\left(12^{\text {x }}\right.$ ) | 3.246 (13) |
| $\mathrm{O}\left(2^{\text {i }}\right.$ ) $-\mathrm{Cu}-\mathrm{O}\left(3^{\text {y }}\right.$ ) | 95.9 (2) | $\mathrm{O}\left(3^{\text {xiii }}\right)-\mathrm{Si}(2)-\mathrm{O}\left(9^{\text {x }}\right.$ | 111.5 (3) |
| $\mathrm{O}\left(2^{2}\right)-\mathrm{Cu}-\mathrm{O}\left(8^{\text {iii) }}\right.$ ) | 92.0 (3) | $\mathrm{O}\left(7^{\text {ix }}\right)-\mathrm{Si}(2)-\mathrm{O}\left(9^{\text {x }}\right.$ ) | 106.4 (4) |
| $\mathrm{O}\left(3^{3 i}\right)-\mathrm{Cu}-\mathrm{O}(3)$ | 79.1 (2) | $\mathrm{O}(4)-\mathrm{Si}(3)-\mathrm{O}\left(5^{\text {xiv }}\right.$ ) | 111.3 (3) |
| $\mathrm{O}\left(3^{\text {ii) }}-\mathrm{Cu}-\mathrm{O}\left(8^{\text {iii }}\right.\right.$ ) | 94.9 (3) | $\mathrm{O}(4)-\mathrm{Si}(3)-\mathrm{O}\left(6^{\text {xij }}\right)$ | 112.1 (4) |
| $\mathrm{O}\left(2^{\text {2iii) }}\right.$ - $\mathrm{Si}(1)-\mathrm{O}\left(4^{\text {xii) }}\right)$ | i) 108.4 (4) | $\mathrm{O}(4)-\mathrm{Si}(3)-\mathrm{O}\left(10^{\prime}\right)$ | 109.0 (5) |
| $\mathrm{O}\left(2^{\text {iii) }}\right.$ - $-\mathrm{Si}(1)-\mathrm{O}\left(7^{\text {iii) }}\right)$ | ) 112.3 (3) | $\mathrm{O}\left(5^{\text {xiv }}\right.$ - $-\mathrm{Si}(3)-\mathrm{O}\left(6^{\text {vi }}\right)$ | 108.7 (3) |
| $\mathrm{O}\left(2^{2 i i}\right)-\mathrm{Si}(1)-\mathrm{O}\left(11^{\prime}\right)$ | i) 115.1 (5) | $\mathrm{O}\left(5^{\text {xiv }}\right)-\mathrm{Si}(3)-\mathrm{O}\left(10^{\text {i }}\right)$ | 109.7 (5) |
| $\mathrm{O}\left({ }^{\text {xii] }}-\mathrm{Si}(1)-\mathrm{O}\left(7^{\text {iii }}\right)\right.$ | (i) 107.8 (3) | $\mathrm{O}\left(6^{\text {ij }}\right)-\mathrm{Si}(3)-\mathrm{O}\left(10^{\prime}\right)$ | 105.9 (6) |
| $\mathrm{O}\left(4^{\text {xii) }}\right.$ - $\mathrm{Si}(1)-\mathrm{O}\left(11^{\text {i }}\right.$ ) | (1) 106.3 (4) | $\mathrm{O}\left(6^{\text {iii }}\right)-\mathrm{Si}(4)-\mathrm{O}\left(\right.$ 8 $\left.^{\text {iiii }}\right)$ | 114.0 (4) |
| $\mathrm{O}\left(\mathrm{7}^{\text {ii) }}\right.$ - $-\mathrm{Si}(1)-\mathrm{O}\left(11^{\prime}\right)$ | (i) 106.6 (4) | $\mathrm{O}\left(6^{\text {iii] }}\right.$ - $\mathrm{Si}(4)-\mathrm{O}\left({ }^{\text {(9iii) }}\right.$ ) | 103.9 (3) |
| $\mathrm{O}(1)-\mathrm{Si}(2)-\mathrm{O}\left(3^{\text {iii) }}\right.$ ) | ) 113.2 (5) | $\mathrm{O}\left(6^{\text {iii) }}\right.$-Si(4)-O(12) | 106.4 (6) |
| $\mathrm{O}(1)-\mathrm{Si}(2)-\mathrm{O}\left(7^{\text {ix }}\right.$ ) | 107.5 (4) | $\mathrm{O}\left(8^{\text {xiii) }}\right.$ - $\mathrm{Si}(4)-\mathrm{O} 9^{\text {xiii) }}$ ) | ) 112.1 (4) |
| $\mathrm{O}(1)-\mathrm{Si}(2)-\mathrm{O}\left(9^{* v}\right)$ | 107.4 (5) | $\mathrm{O}\left(8^{\text {xiii) }}-\mathrm{Si}(4)-\mathrm{O}(12)\right.$ | 116.5 (6) |
| $\mathrm{O}\left(3^{\text {iiii }}\right)-\mathrm{Si}(2)-\mathrm{O}\left(7^{\text {ix }}\right)$ | ) 110.6 (4) | $\mathrm{O}\left(9^{\text {xiii }}-\mathrm{Si}(4)-\mathrm{O}(12)\right.$ | 102.6 (5) |

Symmetry code: (i) $1-x,-\frac{1}{2}+y, 1-z$; (ii) $x, \frac{1}{2}-y, 1+z$; (iii) 1 $-x, 1-y, 1-z$; (iv) $1-x, 2-y, 1-z$; (v) $1-x, \frac{1}{2}+y, 1-z$; (vi) $-1+x,-1+y, z$; (vii) $-1+x, \frac{3}{2}-y, z$; (viii) $-x, 1-y, 1-$ $z$; (ix) $x, \frac{3}{2}-y, z$; (x) $x, y, 1+z$; (xi) $-x,-\frac{1}{2}+y, 1-z$; (xii) $1-x$, $-y, 1-z$; (xiii) $x, \frac{1}{2}-y, z$; (xiv) $1+x, y, z$; (xv) $1-x, 1-y,-z$; (xvi) $x,-1+y, z$.
repeating unit along the shortest period of the cell. $\mathrm{CuO}_{4}$ squares share corners with $\mathrm{SiO}_{4}$ tetrahedra. Two kinds of Rb atom site have eight and ten nearest O -atom neighbours, respectively, and are located in the cavity of the six-membered rings.

The interatomic distances and bond angles are listed in Table 2. $\mathrm{Si}-\mathrm{O}$ and $\mathrm{Cu}-\mathrm{O}$ distances agree with previous data (Kawamura \& Kawahara, 1976;

1977; Kawamura, Kawahara \& Iiyama, 1978; Kawamura \& liyama, 1981; Heinrich \& Gramlich, 1982). In the $\mathrm{SiO}_{4}$ double sheets, the bridging $\mathrm{Si}-\mathrm{O}$ distance to other Si atoms (mean $1.626 \AA$ ) is significantly longer than those to Cu and Rb atoms (mean $1.578 \AA$ ). The average $\mathrm{Si}-\mathrm{O}$ distances for the four $\mathrm{SiO}_{4}$ tetrahedra are $1.617,1.617,1.593$ and $1.608 \AA$, and the distortion indices, $\left[d(M-\mathrm{O})_{\text {max }}-d(M-\right.$ $\left.\mathrm{O})_{\min }\right] /\langle d(M-\mathrm{O})\rangle$, of $\mathrm{SiO}_{4}$ tetrahedra (Liebau, 1985 ) are $3.92 \times 10^{-2}, 1.98 \times 10^{-2}, 2.02 \times 10^{-2}$ and $6.34 \times 10^{-2}$, respectively. The bonding of $\mathrm{SiO}_{4}$ tetrahedra and $\mathrm{CuO}_{4}$ squares is directional and rigid compared with $\mathrm{Rb}-\mathrm{O}$ polyhedra, which are irregular in shape and have ionic character. Accordingly, the latter are considered to compensate for all the strains resulting from the framework constructed by these rigid and rather covalent $s p^{3}$ tetrahedra of $\mathrm{SiO}_{4}$ and the $d s p^{2}$ planar $\mathrm{CuO}_{4}$ squares. Here the alkali metals may play an important role in the stabilization of the structure. In fact, the number of phases containing $A_{x} \mathrm{Cu}_{y} \mathrm{Si}_{p} \mathrm{O}_{q}(A=$ alkali metal) is much larger than that containing only $\mathrm{Cu}_{x} \mathrm{Si}_{p} \mathrm{O}_{q}$.

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# Structure of Potassium Paradodecatungstate $7 \frac{1}{2}$-Hydrate 

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$77.77(2)^{\circ}, V=2436.4 \AA^{3}, Z=2, D_{x}=4.645 \mathrm{~g} \mathrm{~cm}^{-3}$, $\lambda($ Mo $K \alpha)=0.7107 \AA, \quad \mu=280.5 \mathrm{~cm}^{-1}, \quad F(000)=$ 2982, $T=296 \mathrm{~K}, R=0.051, w R=0.067$ and $S=$


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[^1]:    * Lists of structure factors and anisotropic thermal parameters have been deposited with the British Library Document Supply Centre as Supplementary Publication No. SUP 55777 (12 pp.). Copies may be obtained through The Technical Editor, International Union of Crystallography, 5 Abbey Square, Chester CH1 2 HU , England. [CIF reference: OH 1000 ]

